

**Electronic Filing System (EFS) Data**  
**Electronic Patent Application Submission**  
**USPTO Use Only**

EFS ID: 63514

Application ID: 10710244



Title of Invention:

STRUCTURES AND METHODS FOR  
MANUFACTURING P-TYPE  
MOSFET WITH GRADED  
EMBEDDED SILICON-GERMANIUM  
SOURCE-DRAIN AND/OR  
EXTENSION

First Named Inventor: Huilong Zhu

Domestic/Foreign Application: Domestic Application

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Submission Type: Utility Patent Filing

Filing Type: new-utility

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PATENT APPLICATION SERIAL NO. \_\_\_\_\_

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE  
FEE RECORD SHEET

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01 FC:1001 770.00 DA  
02 FC:1202 90.00 DA

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